N-Channel Silicon MOSFET



2SK2152

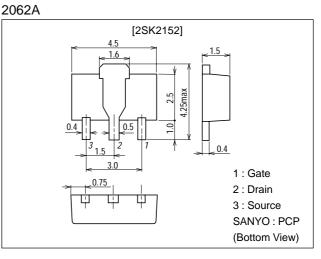
Ultrahigh-Speed Switching Applications

Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		20	V
Gate-to-Source Voltage	VGSS		±15	V
Drain Current (DC)	ID		2	A
Drain Current (pulse)	I _{DP}	PW≤10µs, duty cycle≤1%	8	A
Allowable Power Dissipation	P-	Tc=25°C	3.5	W
	PD	Mounted on a ceramic board (250mm ² ×0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0	20			V
Gate-to-Source Breakdown Voltage	V(BR)GSS	I _G =±100µA, V _{DS} =0	±15			V
Zero-Gate Votlage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0			100	μA
Gate-to-Source Leakage Current	IGSS	V _{GS} =±12V, V _{DS} =0			±10	μA
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.0		2.0	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =1A	1.2	2		S
Static Drain-to-Source On-State Resistance	R _{DS(on)} 1	I _D =1A, V _{GS} =10V		130	180	mΩ
	R _{DS(on)} 2	ID=1A, VGS=4V		170	250	mΩ
Marking : KJ				Continued on next page.		

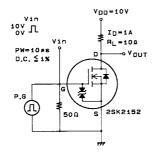
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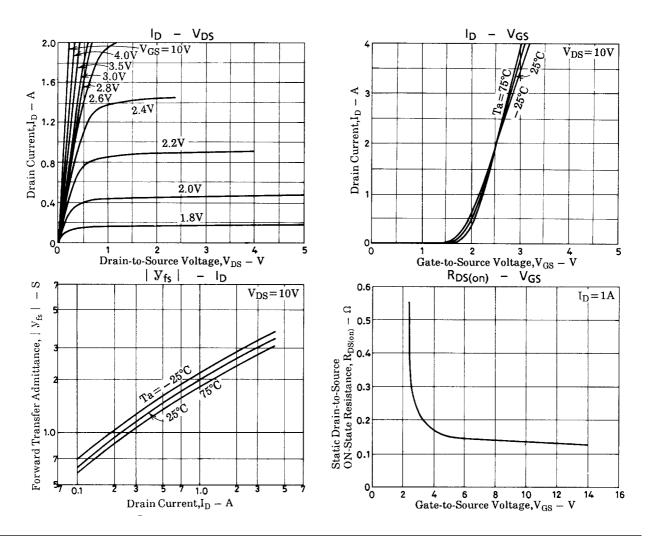
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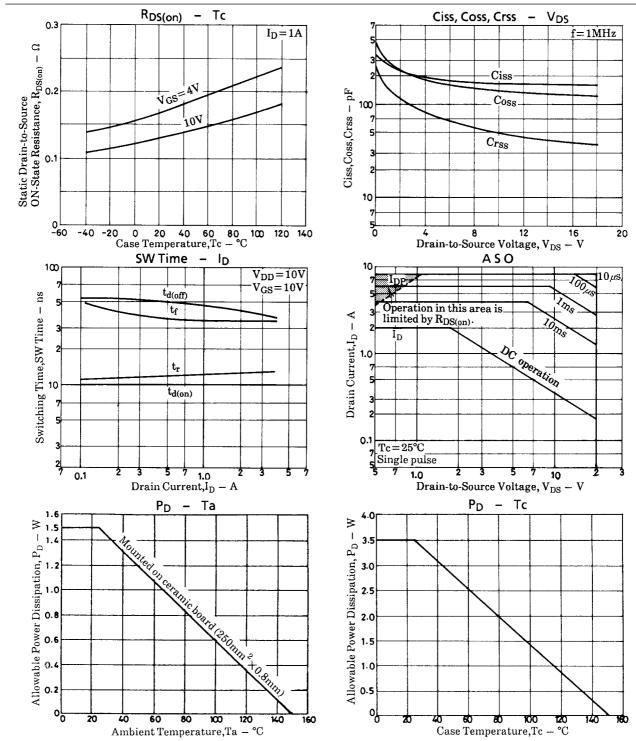
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		170		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		145		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		50		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit		10		ns
Rise Time	tr	See specified Test Circuit		12		ns
Turn-OFF Delay Time	^t d(off)	See specified Test Circuit		50		ns
Fall Time	tf	See specified Test Circuit		35		ns
Diode Forward Voltage	V _{SD}	I _S =2A, V _{GS} =0		1.0		V

Switching Time Test Circuit







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